

Landolt-Börnstein Substance/Property Index

III/41: Semiconductors

(revised and extended contents of the volumes III/17 and III/22)

Subvolume III/41B: II-VI and I-VII compounds, semimagnetic compounds

General Introduction

List of substances

Compounds with two elements

[II-VI compounds, general data](#)

[I-VII compounds, general data](#)

[II-V manganese compounds,
general data](#)

[AgBr](#)

[AgCl](#)

[AgF](#)

[AgI](#)

[BaO](#)

[BaS](#)

[Be-VI compounds, general data](#)

[BeO](#)

[BeS](#)

[BeSe](#)

[BeTe](#)

[CaO](#)

[CaS](#)

[CdO](#)

[CdS](#)

[CdSe](#)

[CdTe](#)

[\$\gamma\$ -CuBr](#)

[\$\gamma\$ -CuCl](#)

[CuF](#)

[\$\gamma\$ -CuI](#)

[HgO](#)

[HgS](#)

[HgSe](#)

[HgTe](#)

[MgO](#)

[MgS](#)

[MgSe](#)

[MgTe](#)

[SrO](#)

[ZnO](#)

[ZnS](#)

[ZnSe](#)

[ZnTe](#)

Compounds with three elements

[semimagnetic semiconductors, general data](#)

[Ca_xBa_{1-x}S](#)

[Cd_xCa_{1-x}O](#)

[Cd_{1-x}Co_xS](#)

[Cd_{1-x}Co_xSe](#)

[Cd_{1-x}Co_xTe](#)

[Cd_{1-x}Cr_xS](#)

[Cd_{1-x}Cr_xTe](#)

[Cd_{1-x}Fe_xS](#)

[Cd_{1-x}Fe_xSe](#)

[Cd_{1-x}Fe_xTe](#)

[\(Cd_{1-x}Mn_x\)₃As₂](#)

[Cd_{1-x}Mn_xS](#)

[Cd_{1-x}Mn_xSe](#)

[Cd_{1-x}Mn_xTe](#)

[Cd_{1-x}Ni_xTe](#)

[CdS_{1-x}Se_x](#)

[CdS_{1-x}Te_x](#)

[CdSe_xTe_{1-x}](#)

[Cd_xSr_{1-x}O](#)

[Ga_{1-x}Mn_xAs](#)

[Ge_{1-x}Mn_xTe](#)

[Hg_{1-x}Cd_xSe](#)

[Hg_{1-x}Cd_xTe](#)

[Hg_{1-x}Co_xSe](#)

[Hg_{1-x}Cr_xSe](#)

[Hg_{1-x}Fe_xS](#)

[Hg_{1-x}Fe_xSe](#)

[Hg_{1-x}Fe_xTe](#)

[Hg_{1-x}Mn_xS](#)

[Hg_{1-x}Mn_xSe](#)

[Hg_{1-x}Mn_xTe](#)

[Hg_{1-x}Zn_xTe](#)

[In_{1-x}Mn_xAs](#)

[Mg_xCa_{1-x}O](#)

[Pb_{1-x}Eu_xS](#)

[Pb_{1-x}Eu_xSe](#)

[Pb_{1-x}Eu_xTe](#)

[Pb_{1-x}Gd_xTe](#)

[Pb_{1-x}Mn_xS](#)

[Pb_{1-x}Mn_xSe](#)

[Pb_{1-x}Mn_xTe](#)

[Sn_{1-x}Gd_xTe](#)

[Sn_{1-x}Mn_xTe](#)

[Sr_xBa_{1-x}O](#)

[Sr_xCa_{1-x}S](#)

[Zn_xCd_{1-x}O](#)

[Zn_xCd_{1-x}S](#)

[Zn_xCd_{1-x}Se](#)

[Zn_xCd_{1-x}Te](#)

[Zn_{1-x}Co_xS](#)

[Zn_{1-x}Co_xSe](#)

[Zn_{1-x}Co_xTe](#)

[Zn_{1-x}Cr_xS](#)

[Zn_{1-x}Cr_xSe](#)

[Zn_{1-x}Cr_xTe](#)

[Zn_{1-x}Fe_xS](#)

[Zn_{1-x}Fe_xSe](#)

[Zn_{1-x}Fe_xTe](#)

[Zn_xHg_{1-x}Se](#)

[\(Zn_{1-x}Mn_x\)₃As₂](#)

[Zn_{1-x}Mn_xS](#)

[Zn_{1-x}Mn_xSe](#)

[Zn_{1-x}Mn_xTe](#)

[Zn_{1-x}Ni_xS](#)

[Zn_{1-x}Ni_xSe](#)

[ZnS_{1-x}Se_x](#)

[ZnS_{1-x}Te_x](#)

[ZnSe_xTe_{1-x}](#)

Compounds with four elements

[Cd_xHg_yMn_zSe](#)

[Cd_xHg_yMn_zTe](#)

[Cd\(Te,Se,S\)](#)

[Cd_xZn_yMn_zTe](#)

[Hg_{1-x}Mn_xTe_{1-y}Se_y](#)

[Pb_{1-x-y}Sn_yMn_xSe](#)

[Pb_{1-x-y}Sn_yMn_xTe](#)

[Zn_{1-y}Cd_yS_xSe_{1-x}](#)

[Zn_{1-y}Cd_ySe_xTe_{1-x}](#)

[Zn\(Te,Se,S\)](#)

Silver bromide (AgBr)

[back to top](#)

[band structure](#)

[band gap, indirect edge](#)

[exciton energies](#)

[g-factors](#)

[band gap, direct edge](#)

[effective masses](#)

[deformation potentials and related parameters](#)

[biexciton parameters](#)

[further remarks to electronic properties](#)

[impurities and intrinsic defects: bound excitons](#)

[impurities and intrinsic defects: infrared absorption spectra](#)

[impurities and intrinsic defects: transient infrared absorption spectra](#)

[crystal structure, high pressure modifications, lattice parameters, thermal expansion](#)

[phonon dispersion](#)

[phonon frequencies and wavenumbers, Debye-Waller factors and related data](#)

[elastic moduli and compliances](#)

[Grüneisen parameters, bulk modulus, compressibility](#)

[electrical and ionic transport properties](#)

[optical properties, dielectric constants](#)

[Debye temperature, heat capacity, melting point, density](#)

[physical properties of AgBr\(1-x\)Cl\(x\) and AgBr\(1-x\)I\(x\) mixed crystals](#)

Silver chloride (AgCl)

[back to top](#)

[Debye temperature, heat capacity, melting point, density](#)

[band structure](#)

[energy gaps, indirect edge](#)

[deformation potential](#)

[exciton binding energy, exchange interaction, g-factor](#)

[energy gaps, direct edge](#)

[effective masses, further band parameters](#)

[further remarks to band structure](#)

[impurities and intrinsic defects: bound excitons](#)

[impurities and intrinsic defects: infrared absorption spectra](#)

[impurities and intrinsic defects: transient infrared absorption spectra](#)

[impurities and intrinsic defects: self-trapped exciton and hole state \(STE, STH\)](#)

[impurities and intrinsic defects: ODMR spectra](#)

[crystal structure, lattice parameters, thermal expansion](#)

[phonon dispersion, frequencies and wavenumbers](#)

[elastic moduli and compliances](#)

[bulk modulus, compressibility, mode Grüneisen parameters](#)

[electrical and thermal transport](#)

[refractive index, dielectric constants](#)

[reflectivity, luminescence](#)

Silver monofluoride (AgF)

[back to top](#)

[characterization, band structure and energies](#)

[crystal structure, lattice parameters, phonon frequencies](#)

[dielectric constants, refractive index](#)

[Debye temperature, melting point, density](#)

Silver iodide (AgI)[back to top](#)[band structure, energy gaps: beta-AgI \(wurtzite\)](#)[edge exciton transition energies: beta-AgI \(wurtzite\)](#)[transitions to higher excited exciton states: beta-AgI \(wurtzite\)](#)[spin-orbit, crystal field and longitudinal-transverse splitting energies \(beta-AgI\)](#)[exciton radius and binding energies](#)[effective and reduced masses](#)[electronic properties of beta-AgI \(zincblende\)](#)[electronic properties of f.c.c.-AgI \(NaCl-type\)](#)[crystal structure, high pressure modifications, lattice parameters](#)[phonon dispersion and frequencies, Debye-Waller factors](#)[sound velocities, elastic moduli and compliances, compressibility and related data](#)[lattice properties of gamma-AgI and f.c.c.-AgI](#)[ionic transport and related properties](#)[dielectric constants](#)[piezoelectric stress coefficient](#)[far-infrared reflectivity and transmission](#)[Debye temperature, melting point, density, heat capacity](#)[AgBr\(1-x\)I\(x\), AgI\(1-x\)Cl\(x\) and Ag\(x\)Cu\(1-x\)I mixed crystals](#)**Barium oxide (BaO)**[back to top](#)[band structure, energy gap](#)[effective masses, Fröhlich coupling constant](#)[impurities and defects](#)[crystal structure, lattice parameters, thermal expansion](#)[phonon dispersion and phonon frequencies](#)[sound velocities, elastic moduli](#)[bulk modulus, effective ion charge](#)[electrical and thermal transport properties](#)[dielectric constants, optical and photoelectric properties](#)[magnetic properties](#)[Debye temperature, heat capacity, density, melting and boiling points](#)[thermodynamical properties](#)**Barium sulfide (BaS)**[back to top](#)[physical properties](#)**Beryllium oxide (BeO)**[back to top](#)[electronic properties](#)[impurities and defects](#)[lattice properties](#)[transport and optical properties](#)[optical properties](#)[further properties](#)**Beryllium sulfide (BeS)**[back to top](#)[physical properties](#)**Beryllium selenide (BeSe)**[back to top](#)[physical properties](#)

Beryllium telluride (BeTe)

[physical properties](#)

[back to top](#)

Beryllium compounds (Be-VI)

[general properties](#)

[back to top](#)

Ca(x)Ba(1-x)S

[properties of IIA-VIB compounds](#)

[back to top](#)

Calcium oxide (CaO)

[band structure](#)

[energy gap, interband transition energies](#)

[effective and polaron masses, Fröhlich coupling constant](#)

[impurities and defects](#)

[crystal structure, lattice parameters, thermal expansion](#)

[phonon dispersion and phonon frequencies](#)

[sound velocities, elastic moduli](#)

[Young's, shear and bulk modulus, Poisson's ratio](#)

[compressibility, Grueneisen parameter, effective ion charge](#)

[electrical and thermal transport properties](#)

[dielectric constants, optical properties](#)

[magnetic properties](#)

[Debye temperature, heat capacity, density, melting and boiling points, hardness](#)

[thermodynamic properties](#)

[back to top](#)

Calcium sulfide (CaS)

[physical properties](#)

[back to top](#)

Cadmium cobalt sulfide (Cd(1-x)Co(x)S)

[physical properties](#)

[back to top](#)

Cadmium cobalt selenide (Cd(1-x)Co(x)Se)

[physical properties](#)

[back to top](#)

Cadmium cobalt telluride (Cd(1-x)Co(x)Te)

[physical properties](#)

[back to top](#)

Cadmium chromium sulfide (Cd(1-x)Cr(x)S)

[physical properties](#)

[back to top](#)

Cadmium chromium telluride (Cd(1-x)Cr(x)Te)

[physical properties](#)

[back to top](#)

Cadmium iron sulfide (Cd(1-x)Fe(x)S)

[physical properties](#)

[back to top](#)

Cadmium iron selenide (Cd(1-x)Fe(x)Se) physical properties	back to top
Cadmium iron telluride (Cd(1-x)Fe(x)Te) physical properties	back to top
Cadmium manganese sulfide (Cd(1-x)Mn(x)S) physical properties	back to top
Cadmium manganese selenide (Cd(1-x)Mn(x)Se) physical properties	back to top
Cadmium manganese telluride (Cd(1-x)Mn(x)Te) electronic properties lattice, transport and magnetic properties	back to top
Cadmium manganese arsenide: (Cd(1-x)Mn(x))₃As₂ physical properties	back to top
Cd(1-x)Ni(x)Te general properties	back to top
Cd(Te,Se,S) physical properties	back to top
Cd(x)Ca(1-x)O properties of IIA-VIB compounds	back to top
Cd(x)Hg(y)Mn(z)Se physical properties	back to top
Cd(x)Hg(y)Mn(z)Te physical properties	back to top
Cd(x)Sr(1-x)O properties of IIA-VIB compounds	back to top
Cd(x)Zn(y)Mn(z)Te physical properties	back to top
Cadmium oxide (CdO) band structure band energies at symmetry points energy gap	back to top

[interband transition energies](#)
[effective masses, g-factor and related parameters](#)
[impurities and defects](#)
[crystal structure, lattice parameters, thermal expansion](#)
[phonon properties and frequencies, effective ion charge](#)
[transport properties, carrier mobilities](#)
[optical and photoelectric properties, dielectric constants, plasmon energy](#)
[magnetic properties](#)
[Debye temperature, heat capacity, melting point, density](#)
[thermodynamic properties, vapor pressure, phase diagram](#)

Cadmium sulfide (CdS)

[back to top](#)

[band structure, hexagonal modification](#)
[valence band energies, hexagonal modification](#)
[energy gaps, hexagonal modification](#)
[splitting parameters, hexagonal modification](#)
[k-linear terms, hexagonal modification](#)
[energy gap pressure and temperature coefficients, hexagonal modification](#)
[interband transition energies, hexagonal modification](#)
[deformation potentials, hexagonal modification](#)
[free carrier effective masses, hexagonal modification](#)
[g-factors, hexagonal modification](#)
[diamagnetic shift, Luttinger parameter, deformation potentials,](#)
[free excitons, hexagonal modification](#)
[further exciton energies, hexagonal modification](#)
[exciton polaritons: A-exciton, hexagonal modification](#)
[exciton polaritons: B-exciton, hexagonal modification](#)
[dense exciton systems, hexagonal modification](#)
[biexciton energy, hexagonal modification](#)
[electron-hole liquids, highly excited CdS, hexagonal modification](#)
[further exciton data, exciton-phonon coupling, oscillator strengths and other parameters](#)
[band structure, energy gap, cubic modification](#)
[interband transition energies and effective masses, cubic modification](#)
[band structure, zincblende modification](#)
[ionization and excitation energies of impurities and defects](#)
[capture cross-sections of impurities](#)
[further data on impurities](#)
[impurity \(defect\) bound excitons](#)
[donor-acceptor pairs transitions](#)
[crystal structure, modifications](#)
[lattice parameters, thermal expansion](#)
[phonon dispersion](#)
[phonon wavenumbers, mean square displacements](#)
[Raman wavenumbers](#)
[local modes](#)
[sound velocities and absorption](#)
[elastic moduli and compliances](#)
[piezoelectric stress and strain coefficients](#)
[electromechanical coupling factor](#)
[vibrational amplitudes, bulk modulus](#)
[compressibilities, Grueneisen parameters, effective charges](#)
[transport mechanism](#)

[intrinsic conductivity and carrier concentrations](#)
[electrical and thermal conductivity, resistivity, magnetoresistance](#)
[photoconductivity](#)
[electron mobilities](#)
[hole mobilities](#)
[diffusion of carriers and ions](#)
[Seebeck and Nernst coefficient](#)
[optical properties \(general\), refractive index and birefringence, Sellmeier coefficients](#)
[absorption coefficient, reflectance](#)
[dielectric constants](#)
[Verdet constant](#)
[photoelastic coefficient, nonlinear optics](#)
[two photon absorption](#)
[optical rectification and bistability](#)
[linear and quadratic electrooptic coefficients](#)
[Schottky barrier heights](#)
[optical and ESR spectra of iron-group-element-impurities](#)
[magnetic properties](#)
[Debye temperature, heat capacity, density, melting point, hardness](#)
[thermodynamic properties, vapor pressure, phase diagram](#)

CdS(1-x)Se(x)

[back to top](#)

[electronic properties](#)
[impurities and defects, lattice and transport properties](#)
[optical properties](#)

CdS(1-x)Te(x)

[back to top](#)

[physical properties](#)

Cadmium selenide (CdSe)

[back to top](#)

[band structure, hexagonal modification](#)
[energy gaps, hexagonal modification](#)
[valence band splitting parameters, hexagonal modification](#)
[energy gap, temperature and pressure coefficients, hexagonal modification](#)
[interband transition energies, hexagonal modification](#)
[Luttinger parameters, deformation potentials, hexagonal modification](#)
[effective masses, Fröhlich coupling constant, hexagonal modification](#)
[g-factors, hexagonal modification](#)
[exciton energies, hexagonal modification](#)
[excitonic polaritons, oscillator strengths, biexcitons, hexagonal modification](#)
[dense exciton systems, hexagonal modification](#)
[electronic properties, cubic modification](#)
[electronic properties, zincblende modification](#)
[impurities and defects: ionization energies](#)
[further data on shallow and deep impurities](#)
[impurity bound excitons](#)
[crystal structure, modifications](#)
[lattice parameters, thermal expansion](#)
[phonon dispersion](#)
[phonon wavenumbers, mean square displacements](#)

[local mode wavenumbers](#)
[sound velocities](#)
[elastic moduli](#)
[piezoelectric strain and stress coefficients, electromechanical coupling factor](#)
[Young's and bulk modulus, compressibility, effective charges](#)
[electrical transport](#)
[electrical conductivity, carrier concentration, magnetoresistance](#)
[photoconductivity and thermal conductivity](#)
[electron mobilities](#)
[hole mobility, carrier and ion diffusion](#)
[thermoelectric power](#)
[optical properties, general, refractive index](#)
[isotopic wavelength, Sellmeier coefficients](#)
[refractive index, birefringence](#)
[absorption, reflection, luminescence](#)
[dielectric constants](#)
[two photon absorption](#)
[optical and ESR spectra of iron-group element impurities](#)
[electrooptic and non-linear coefficients](#)
[magnetic properties](#)
[Debye temperature, heat capacity, density, melting point, hardness](#)
[thermodynamical properties, phase diagram](#)

CdSe(x)Te(1-x)

[back to top](#)

[electronic properties](#)
[impurities and defects](#)
[transport and optical properties](#)

Cadmium telluride (CdTe)

[back to top](#)

[band structure](#)
[band energies at symmetry points](#)
[energy gap](#)
[critical point and splitting energies](#)
[effective masses](#)
[g-factors, k-linear terms](#)
[Kane and Luttinger parameters of valence band, polaron coupling constant](#)
[deformation potentials](#)
[excitons](#)
[impurities and defects: ionization energies](#)
[intrinsic defects and defect complexes](#)
[energy position and capture cross sections of traps](#)
[bound excitons, donor-acceptor pairs](#)
[crystal structure, modifications](#)
[lattice parameter, thermal expansion](#)
[phonon dispersion, phonon frequencies and wavenumbers, local modes, mean square displacements](#)
[sound velocities, elastic moduli](#)
[bulk modulus, compressibility, ionicity, effective ion charge](#)
[Grüneisen parameter, stress and strain coefficient](#)
[electrical and thermal transport, carrier mobilities](#)
[optical properties, refractive index, dielectric constants, two-photon absorption](#)
[Debye temperature, heat capacity, density, melting point, hardness](#)
[thermodynamic properties, vapor pressure, phase diagram](#)

Cuprous fluoride (CuF)

[back to top](#)

[physical properties](#)

Gallium manganese arsenide (Ga(1-x)Mn(x)As)

[back to top](#)

[physical properties](#)

Cuprous bromide (gamma-CuBr)

[back to top](#)

[lattice parameters, thermal expansion](#)

[band structure, energy gaps](#)

[exciton energies](#)

[higher exciton states](#)

[edge exciton energies](#)

[exciton splitting energies](#)

[spin-orbit splitting energy](#)

[exciton exchange energies](#)

[exciton radii, binding energies and other exciton parameters](#)

[effective masses](#)

[biexciton parameters](#)

[Luttinger parameters, g-factors](#)

[deformation potentials](#)

[electronic properties of NaCl-type CuBr](#)

[crystal structure, high-pressure modifications](#)

[phonon dispersion and frequencies, Debye-Waller factor](#)

[elastic moduli](#)

[compressibility, bulk modulus, internal strain, Grueneisen parameter, effective charges](#)

[ionic conductivity](#)

[dielectric constants, refractive index](#)

[birefringence, electrooptic and elasto-optic constants](#)

[second order nonlinear parameters](#)

[magnetic susceptibility](#)

[Debye temperature, heat capacity, melting point, density](#)

Cuprous chloride (gamma-CuCl)

[back to top](#)

[transition energies to higher excited exciton states](#)

[exciton splitting energies](#)

[spin-orbit splitting energies](#)

[exchange energies](#)

[exciton radii and binding energy](#)

[mean square displacements, Debye-Waller factors, line widths](#)

[biexcitons](#)

[free carrier effective masses](#)

[exciton effective masses](#)

[g-factors](#)

[deformation potentials](#)

[localized excitons](#)

[further remarks to electronic properties](#)

[electronic properties of NaCl-type CuCl](#)

[crystal structure, space group](#)

[lattice parameter, thermal expansion, compressibility](#)

[phonon dispersion](#)

[phonon frequencies, wavenumbers and related data](#)
[elastic moduli, mode Grueneisen parameters, effective charges](#)
[compressibility, bulk modulus, internal strain parameter](#)
[ambipolar diffusion of excitons](#)
[ionic conductivity](#)
[optical properties, dielectric constants, refractive index](#)
[piezoelectric stress coefficient](#)
[electrooptic and piezooptic constants, piezobirefringence](#)
[second-order nonlinear dielectric susceptibility](#)
[third-order nonlinear dielectric susceptibility electromagnetic coupling constant](#)
[magnetic susceptibility](#)
[Debye temperature, melting point, density](#)
[band structure](#)
[energy gaps](#)
[critical point energies](#)
[exciton energies, oscillator strength, polariton dispersion](#)

Cuprous iodide (γ -CuI)

[back to top](#)

[lattice parameters, thermal expansion](#)
[band structure, energy gap](#)
[exciton transition and splitting energies](#)
[spin-orbit splitting energy](#)
[exciton radii, binding energy and other exciton parameters](#)
[effective masses](#)
[g-factors](#)
[deformation potentials](#)
[electronic properties of NaCl-type CuI](#)
[crystal structure, high pressure modifications](#)
[phonon dispersion and frequencies and related data, Debye-Waller factors](#)
[elastic moduli, compressibility, bulk modulus, internal strain, Grueneisen parameter, effective charge](#)
[ionic conductivity](#)
[dielectric constants, refractive index](#)
[birefringence, piezoelectric, piezooptic and other optical constants](#)
[magnetic susceptibility](#)
[Debye temperature, heat capacity, melting point, density](#)

Germanium manganese telluride ($\text{Ge}(1-x)\text{Mn}(x)\text{Te}$)

[back to top](#)

[physical properties](#)

Hg(1-x)Cd(x)Se

[back to top](#)

[electronic properties](#)
[lattice properties](#)
[transport and optical properties](#)

Hg(1-x)Cd(x)Te

[back to top](#)

[band structure, energy gap](#)
[interband transition energies, further band parameters](#)
[effective masses](#)
[impurity levels](#)

[lattice properties](#)
[transport properties](#)
[optical properties](#)

Mercury cobalt selenide (Hg(1-x)Co(x)Se)

[back to top](#)

[physical properties](#)

Mercury chromium selenide (Hg(1-x)Cr(x)Se)

[back to top](#)

[physical properties](#)

Mercury iron sulfide (Hg(1-x)Fe(x)S)

[back to top](#)

[physical properties](#)

Mercury iron selenide (Hg(1-x)Fe(x)Se)

[back to top](#)

[physical properties](#)

Mercury iron telluride (Hg(1-x)Fe(x)Te)

[back to top](#)

[physical properties](#)

Mercury manganese sulfide (Hg(1-x)Mn(x)S)

[back to top](#)

[physical properties](#)

Mercury manganese selenide (Hg(1-x)Mn(x)Se)

[back to top](#)

[electronic properties](#)

[transport and magnetic properties](#)

Mercury manganese telluride (Hg(1-x)Mn(x)Te)

[back to top](#)

[band structure, general](#)

[band structure parameters](#)

[effective mass, g-factor, exchange constants](#)

[impurities](#)

[lattice properties, dielectric constants](#)

[transport mechanisms, insulator-metal transition](#)

[optical and magnetic properties](#)

Hg(1-x)Mn(x)Te(1-y)Se(y)

[back to top](#)

[physical properties](#)

Hg(1-x)Zn(x)Te

[back to top](#)

[physical properties](#)

Mercury oxide (HgO)

[back to top](#)

[crystal structure, physical properties](#)

Mercury sulfide (HgS)

[back to top](#)

[crystal structure, modifications](#)

[band energies, impurities: alpha-HgS \(trigonal\) \(red cinnabar\)](#)

[lattice properties: alpha-HgS \(trigonal\) \(red cinnabar\)](#)

[transport properties: alpha-HgS \(trigonal\) \(red cinnabar\)](#)

[optical properties, dielectric constants: alpha-HgS \(trigonal\) \(red cinnabar\)](#)

[crystal structure, lattice parameters, bulk modulus: beta-HgS \(zincblende structure\)](#)

[band structure, energy gap, effective masses: beta-HgS \(zincblende structure\)](#)

[further lattice properties: beta-HgS \(zincblende structure\)](#)

[transport, optical and further properties: beta-HgS \(zincblende structure\)](#)

[Debye temperature, heat capacity, melting point, density, hardness](#)

[thermodynamic properties](#)

Mercury selenide (HgSe)

[back to top](#)

[band structure, energy gap](#)

[interband transition and splitting energies, effective masses, g-factor](#)

[Luttinger and Kane parameters of the valence band](#)

[impurities and defects](#)

[crystal structure, lattice parameters](#)

[phonon dispersion and phonon wavenumbers](#)

[elastic moduli](#)

[effective charge, bulk modulus, compressibility](#)

[electrical conductivity, electron mobility](#)

[optical properties, dielectric constants](#)

[Debye temperature, heat capacity, melting point, density, hardness](#)

[thermodynamical properties, vapor pressure, phase diagram](#)

Mercury telluride (HgTe)

[back to top](#)

[band structure, band energies at symmetry points](#)

[energy gap](#)

[critical point energies](#)

[spin-orbit splitting, k-linear term](#)

[effective masses](#)

[g-factors](#)

[Luttinger and Kane parameters](#)

[impurities and defects](#)

[crystal structure, modifications](#)

[lattice parameters](#)

[thermal expansion](#)

[phonon dispersion, phonon energies and wavenumbers](#)

[elastic moduli, sound velocity](#)

[bulk modulus, effective charge, Grueneisen parameter](#)

[electrical transport, conductivity, mobility](#)

[optical properties, dielectric constants](#)

[Debye temperature, melting point, density, heat capacity, hardness](#)

[thermodynamical properties, vapor pressure, phase diagram](#)

Indium manganese arsenide (In_(1-x)Mn_(x)As)

[back to top](#)

[physical properties](#)

Mg(x)Ca(1-x)O

[properties of IIA-VIB compounds](#)

[back to top](#)

Magnesium oxide (MgO)

[band structure](#)

[energy gap, interband transition energies](#)

[impurities and defects](#)

[crystal structure, lattice parameters, thermal expansion](#)

[phonon dispersion and phonon frequencies](#)

[sound velocities](#)

[elastic moduli](#)

[Young's, shear and bulk moduli, Poisson's ratio](#)

[compressibility, Grueneisen parameter, effective ion charge](#)

[electrical and thermal transport properties](#)

[dielectric constants, optical and photoelectric properties](#)

[magnetic properties](#)

[Debye temperature, heat capacity, density, melting and boiling points, hardness](#)

[thermodynamic parameters](#)

[back to top](#)

Magnesium sulfide (MgS)

[physical properties](#)

[back to top](#)

Magnesium selenide (MgSe)

[physical properties](#)

[back to top](#)

Magnesium telluride (MgTe)

[physical properties](#)

[back to top](#)

Lead europium sulfide (Pb(1-x)Eu(x)S)

[physical properties](#)

[back to top](#)

Lead europium selenide (Pb(1-x)Eu(x)Se)

[physical properties](#)

[back to top](#)

Lead europium telluride (Pb(1-x)Eu(x)Te)

[physical properties](#)

[back to top](#)

Lead gadolinium telluride (Pb(1-x)Gd(x)Te)

[physical properties](#)

[back to top](#)

Lead manganese sulfide (Pb(1-x)Mn(x)S)

[physical properties](#)

[back to top](#)

Lead manganese selenide (Pb(1-x)Mn(x)Se)

[physical properties](#)

[back to top](#)

Lead manganese telluride ($\text{Pb}(1-x)\text{Mn}(x)\text{Te}$) physical properties general properties	back to top
Lead tin manganese selenide ($\text{Pb}(1-x-y)\text{Sn}(y)\text{Mn}(x)\text{Se}$) physical properties	back to top
Lead tin manganese telluride ($\text{Pb}(1-x-y)\text{Sn}(y)\text{Mn}(x)\text{Te}$) physical properties general properties	back to top
Tin gadolinium telluride ($\text{Sn}(1-x)\text{Gd}(x)\text{Te}$) physical properties	back to top
Tin manganese telluride ($\text{Sn}(1-x)\text{Mn}(x)\text{Te}$) physical properties	back to top
$\text{Sr}(x)\text{Ba}(1-x)\text{O}$ properties of IIA-VIB compounds	back to top
$\text{Sr}(x)\text{Ca}(1-x)\text{S}$ properties of IIA-VIB compounds	back to top
Strontium oxide (SrO) band structure, energy gap effective and polaron masses, Fröhlich coupling constant impurities and defects crystal structure, lattice parameters, thermal expansion phonon dispersion and phonon frequencies sound velocities, elastic moduli Young's, shear and bulk modulus, Poisson's ratio compressibility, Grueneisen parameter, effective ion charge electrical and thermal transport properties dielectric constants, optical and photoelectric properties magnetic properties Debye temperature, heat capacity, density, melting and boiling points, hardness . thermodynamical properties	back to top
Zinc cobalt sulfide ($\text{Zn}(1-x)\text{Co}(x)\text{S}$) physical properties	back to top
Zinc cobalt selenide ($\text{Zn}(1-x)\text{Co}(x)\text{Se}$) physical properties	back to top
Zinc cobalt telluride ($\text{Zn}(1-x)\text{Co}(x)\text{Te}$) physical properties	back to top
Zinc chromium sulfide ($\text{Zn}(1-x)\text{Cr}(x)\text{S}$) physical properties	back to top

Zinc chromium selenide ($\text{Zn}_{(1-x)}\text{Cr}_x\text{Se}$) physical properties	back to top
Zinc chromium telluride ($\text{Zn}_{(1-x)}\text{Cr}_x\text{Te}$) physical properties	back to top
Zinc iron sulfide ($\text{Zn}_{(1-x)}\text{Fe}_x\text{S}$) physical properties	back to top
Zinc iron selenide ($\text{Zn}_{(1-x)}\text{Fe}_x\text{Se}$) physical properties	back to top
Zinc iron telluride ($\text{Zn}_{(1-x)}\text{Fe}_x\text{Te}$) physical properties	back to top
Zinc manganese arsenide: ($\text{Zn}_{(1-x)}\text{Mn}_x$)₃As₂ physical properties	back to top
Zinc manganese sulfide ($\text{Zn}_{(1-x)}\text{Mn}_x\text{S}$) physical properties	back to top
Zinc manganese selenide ($\text{Zn}_{(1-x)}\text{Mn}_x\text{Se}$) physical properties	back to top
Zinc manganese telluride ($\text{Zn}_{(1-x)}\text{Mn}_x\text{Te}$) physical properties	back to top
Zn_(1-x)Ni_xS general properties	back to top
Zn_(1-x)Ni_xSe general properties	back to top
Zn_(1-y)Cd_yS_xSe_(1-x) physical properties	back to top
Zn_(1-y)Cd_ySe_xTe_(1-x) physical properties	back to top
Zn(Te,Se,S) physical properties	back to top
Zn_xCd_(1-x)O physical properties	back to top
Zn_xCd_(1-x)S electronic properties impurities and defects lattice parameters, phase diagrams transport properties optical properties	back to top

Zn(x)Cd(1-x)Se

[back to top](#)

[electronic properties](#)
[impurities and defects](#)
[transport properties](#)
[optical properties](#)

Zn(x)Cd(1-x)Te

[back to top](#)

[electronic properties](#)
[impurities and defects](#)
[lattice properties](#)
[transport properties](#)
[optical properties](#)

Zn(x)Hg(1-x)Se

[back to top](#)

[physical properties](#)

Zinc oxide (ZnO)

[back to top](#)

[band structure](#)
[energies of symmetry points of the band structure](#)
[energy gaps](#)
[excitons, general](#)
[exciton transition energies](#)
[further exciton data](#)
[special exciton parameters](#)
[biexcitons](#)
[splitting energies](#)
[electron effective masses](#)
[hole effective masses, g-factors](#)
[deformation potentials](#)
[ionization energies of donors](#)
[ionization energies of shallow impurities](#)
[ionization energies of deep impurities](#)
[deep impurity inner transition energies](#)
[Zeeman behavior of impurity transitions](#)
[isotope shift effects of impurity transitions](#)
[quantum efficiencies eta and decay times tau of impurity transitions](#)
[energy of traps possibly due to acceptors and donors](#)
[excitons bound to neutral acceptors](#)
[excitons bound to neutral donors](#)
[diffusion coefficients](#)
[wavenumbers of absorption peaks](#)
[ESR spectra](#)
[bound excitons](#)
[effective g-values of bound excitons](#)
[crystal structure, lattice parameters](#)
[distances, ionic radii, further lattice parameters](#)
[thermal expansion](#)
[effective ionic charge](#)
[phonon dispersion and related parameters](#)
[phonon wavenumbers: fundamental modes](#)

[phonon wavenumbers: combination modes](#)
[Raman and surface phonon wavenumbers](#)
[sound velocities](#)
[elastic moduli and compliances, bulk modulus, compressibility and related parameters](#)
[piezoelectrical strain and stress coefficients](#)
[electromechanical coupling factor](#)
[pyroelectric constants](#)
[electronic conductivity and photoconductivity](#)
[resistivity, mobility](#)
[thermoelectric power](#)
[surface conductivity](#)
[thermal conductivity](#)
[optical properties and spectra](#)
[refractive index](#)
[isotropic wavelength](#)
[dielectric constants](#)
[electrooptical constants](#)
[light absorption in crystals with admixtures](#)
[nonlinear optical properties](#)
[magnetic susceptibility](#)
[Debye temperature, heat capacity, density, melting point, vapor pressure, hardness](#)
[thermodynamical properties](#)

Zinc sulfide (ZnS)

[back to top](#)

[band structure, cubic modification](#)
[energy gap, cubic modification](#)
[exciton energies, cubic modification](#)
[exciton and electron-hole liquid binding energies, cubic modification](#)
[Fröhlich and exciton-phonon coupling constants cubic modification](#)
[critical point and interband transition energies, cubic modification](#)
[spin-orbit splitting, g-factor, cubic modification](#)
[effective masses, cubic modification](#)
[deformation potential, k-linear term, cubic modification](#)
[band structure, hexagonal modification](#)
[energy gap, hexagonal modification](#)
[exciton energies, hexagonal modification](#)
[interband transition energies, hexagonal modification](#)
[crystal field and spin-orbit splitting, g-factor, hexagonal modification](#)
[effective masses, Luttinger parameters, hexagonal modification](#)
[energy states of imperfections and impurities, general remarks](#)
[shallow donors, ionization energies and g-values](#)
[shallow acceptor energies](#)
[ionization energies of deep impurities](#)
[ionization energies of deep impurities \(further data prior to 1980\)](#)
[deep impurity inner transition energies](#)
[crystal field splitting parameter \$Dq\$ and Racah parameter \$B\$ of 3d impurities](#)
[property: Zeeman behavior of impurity transitions](#)
[isotope shift effects of impurity transitions](#)
[pressure coefficients of impurity transitions](#)
[quantum efficiencies and decay times of impurity transitions](#)
[energy and capture cross section of traps possibly due to acceptors and donors](#)
[emission energies \(maxima of emission bands\) of impurity-related transitions](#)

[native defects: general](#)
[native defects: special defects](#)
[impurities in ZnS: scandium](#)
[impurities in ZnS: titanium](#)
[impurities in ZnS: vanadium](#)
[impurities in ZnS: chromium](#)
[impurities in ZnS: manganese](#)
[impurities in ZnS: iron](#)
[impurities in ZnS: cobalt](#)
[impurities in ZnS: nickel](#)
[impurities in ZnS: copper](#)
[ground state properties of rare-earth ions](#)
[impurities in ZnS: other substitutional impurities](#)
[impurities in ZnS: associates](#)
[impurities in ZnS: further associated defects](#)
[property: impurity \(defect\) bound excitons](#)
[crystal structure, modifications](#)
[lattice parameter, cubic modification](#)
[lattice parameter, hexagonal modification](#)
[lattice parameter, polytypic ZnS and other modifications](#)
[transformation temperature and pressure](#)
[thermal expansion](#)
[interatomic distances, covalent and ion radii](#)
[effective charges](#)
[electronic polarizability, ionicity](#)
[phonon dispersion](#)
[phonon wavenumbers, mean square displacements, cubic modification](#)
[phonon wavenumbers, hexagonal modification](#)
[phonon wavenumbers, polytypic ZnS\(4H\)](#)
[Raman frequencies and wavenumbers](#)
[surface optical phonon wavenumber, cubic modification](#)
[sound velocities](#)
[elastic moduli, cubic modification](#)
[elastic moduli, hexagonal modification](#)
[elastic compliances, cubic modification](#)
[elastic compliances, hexagonal modification](#)
[elastic moduli, pressure dependence](#)
[bulk modulus](#)
[compressibility, effective charges](#)
[third-order elastic constants, Young's modulus, Poisson's ratio, Grueneisen parameters](#)
[electromechanical coupling coefficients](#)
[internal strain, piezoelectric strain and stress constants](#)
[\(photo\)conductivity, resistivity, cubic modification](#)
[carrier mobilities, magnetoresistance, diffusion length, cubic modification](#)
[thermal conductivity](#)
[optical properties](#)
[refractive index, cubic modification](#)
[refractive index, hexagonal modification](#)
[refractive index, polycrystalline ZnS](#)
[bulk-photovoltaic effect, thin films](#)
[dielectric constant, cubic modification](#)
[dielectric constant, hexagonal modification](#)

[electrooptical constants](#)
[elastooptical and piezooptical constants](#)
[third order elastooptical constants](#)
[nonlinear optical coefficients](#)
[photodielectric effect](#)
[energy efficiency of cathodoluminescence](#)
[electron yield, electron affinity](#)
[photoelectric threshold, work function](#)
[plasmon energy of valence band electrons](#)
[absorption and reflection in the uv and ir regions](#)
[Raman and Faraday effects, multi-phonon spectra](#)
[visible luminescence of ZnS](#)
[Debye temperature](#)
[heat capacity](#)
[molar weight and volume, isotopic abundances](#)
[hardness, density](#)
[melting point](#)
[vapor pressure, heat of vaporization](#)
[thermodynamical parameters](#)

ZnS(1-x)Se(x)

[back to top](#)

[electronic properties](#)
[impurities and defects](#)
[lattice properties](#)
[transport properties](#)
[optical properties](#)

ZnS(1-x)Te(x)

[back to top](#)

[physical properties](#)

Zinc selenide (ZnSe)

[back to top](#)

[band structure](#)
[energies at symmetry points of the band structure](#)
[energy gap](#)
[exciton energies](#)
[temperature and pressure dependence of exciton energies](#)
[further exciton parameters](#)
[interband transition energies](#)
[spin-orbit splitting energies](#)
[free carrier effective masses, Fröhlich coupling constant](#)
[exciton reduced masses and other exciton parameters](#)
[Luttinger parameters, exchange parameter](#)
[g-factors](#)
[oscillator strengths](#)
[exciton Rydberg energy](#)
[electron-hole interaction parameter](#)
[k-linear term, deformation potentials](#)
[shallow donors, ionization energies](#)
[shallow donor, excitation energies](#)
[chemical and g-values of shallow impurities](#)

[shallow acceptor ionization energies](#)
[shallow acceptor excitation energies](#)
[further data on shallow impurities](#)
[emission energies](#)
[zero-phonon lines](#)
[bound exciton transition and binding energies](#)
[bound exciton emission peaks](#)
[decay times of acceptor-bound-exciton luminescence](#)
[splitting and g-values of bound excitons](#)
[excitons bound to neutral donors](#)
[transitions into excited electronic states of donor-bound-exciton complexes](#)
[decay times of bound-exciton luminescence](#)
[pressure dependence of bound excitons](#)
[emission band maxima](#)
[energy and capture cross section of traps possibly due to acceptors and donors](#)
[ionization energies of deep impurities](#)
[deep impurity inner transition energies](#)
[pressure coefficients and quantum efficiencies of impurity transitions](#)
[3d impurity emission lines](#)
[3d impurity crystal field splitting](#)
[impurity g-values](#)
[spin Hamiltonian parameters](#)
[crystal structure, modifications](#)
[properties of the rocksalt modification](#)
[lattice parameter, thermal expansion](#)
[ionic radii, effective charges](#)
[phonon dispersion](#)
[phonon energies](#)
[phonon frequencies](#)
[pressure dependence of phonon wavenumbers](#)
[energies of local modes](#)
[sound velocities](#)
[elastic moduli and compliances](#)
[compressibility, piezoelectric stress and strain](#)
[Young's, shear and bulk moduli](#)
[Grüneisen parameters](#)
[electrical \(photo\)conductivity and resistivity](#)
[free carrier mobilities, Hall coefficient and magnetoresistance](#)
[charge carrier and ion diffusion](#)
[thermoelectric power, thermal conductivity](#)
[refractive index](#)
[absorption coefficient](#)
[dielectric constants](#)
[Verdet constant](#)
[Cotton-Mouton effect, electrooptic and photoelastic coefficients](#)
[nonlinear optical properties](#)
[radiation damage](#)
[magnetic properties](#)
[Debye temperature, heat capacity, Schottky barrier heights](#)
[density, melting point, hardness](#)
[thermodynamical properties](#)

ZnSe(x)Te(1-x)

[back to top](#)

[electronic properties](#)

[impurities and defects](#)

[transport and optical properties](#)

Zinc telluride (ZnTe)

[back to top](#)

[band structure, band energies](#)

[energy gap](#)

[exciton energies](#)

[critical point energies, spin-orbit splitting](#)

[effective masses](#)

[Fröhlich coupling constant, g-factors](#)

[diamagnetic shift, k-linear term](#)

[Luttinger parameters, deformation potentials](#)

[shallow acceptor and donor energies](#)

[deep impurities](#)

[bound excitons](#)

[crystal structure, lattice parameters, thermal expansion](#)

[effective charges](#)

[phonon dispersion, phonon frequencies and related data](#)

[sound velocities, elastic moduli, bulk modulus, compressibility](#)

[Grueneisen parameters, internal strain parameter, piezoelectric constant, effective charges](#)

[electrical and thermal transport, carrier mobilities](#)

[dielectric constants](#)

[refractive index, absorption, luminescence](#)

[piezoelectric stress coefficient, photoelastic constants, electrooptic coefficient](#)

[nonlinear optical properties](#)

[heat capacity, Debye temperature, density, melting point, hardness](#)

[thermodynamical properties](#)

II-VI compounds, general data

[back to top](#)

[crystal structure, space group and lattice parameters of IIA-VIB compounds](#)

[crystal structure, space group and lattice parameters of IIB-VIB compounds](#)

[lattices occurring in II-VI compounds](#)

[high temperature and high pressure phases, phase diagrams](#)

[physical properties of Mg, Ca and Ba sulfide](#)

[chemical bond in II-VI compounds](#)

I-VII compounds, general data

[back to top](#)

[comparative tables on crystal structure of phases at normal conditions](#)

[comparative tables on crystal structure of high temperature phases](#)

[chemical bond, disorder and melting](#)

II-V manganese compounds

[back to top](#)

[general properties](#)

Semimagnetic semiconductors, general data

[back to top](#)

[composition and crystal structure of ternary bulk semimagnetic semiconductors](#)

[definitions, general properties, structure, general remarks](#)

[general remarks and important formulae for narrow gap semiconductors](#)

[general remarks and important formulae for wide gap semiconductors](#)

II–VI compounds

crystal structure, space group and lattice parameters of IIA–VIB compounds

crystal structure, space group and lattice parameters of IIB–VIB compounds

lattices occurring in II–VI compounds

high temperature and high pressure phases, phase diagrams

physical properties of Mg, Ca and Ba sulfide

chemical bond in II–VI compounds

beryllium compounds (Be-VI)

general properties

beryllium oxide (BeO)

electronic properties

impurities and defects

lattice properties

transport and optical properties

optical properties

further properties

beryllium sulfide (BeS)

physical properties

beryllium selenide (BeSe)

physical properties

beryllium telluride (BeTe)

physical properties

magnesium oxide (MgO)

band structure

energy gap, interband transition energies

impurities and defects

crystal structure, lattice parameters, thermal expansion

phonon dispersion and phonon frequencies

sound velocities

elastic moduli

Young's, shear and bulk moduli, Poisson's ratio

compressibility, Grüneisen parameter, effective ion charge

electrical and thermal transport properties

dielectric constants, optical and photoelectric properties

magnetic properties

Debye temperature, heat capacity, density, melting and boiling points, hardness

thermodynamic parameters

physical properties (MgS)

physical properties (MgSe)

physical properties (MgTe)

calcium oxide (CaO)

band structure

energy gap, interband transition energies

effective and polaron masses, Fröhlich coupling constant

impurities and defects

crystal structure, lattice parameters, thermal expansion

phonon dispersion and phonon frequencies

sound velocities, elastic moduli

Young's, shear and bulk modulus, Poisson's ratio

compressibility, Grüneisen parameter, effective ion charge

electrical and thermal transport properties

dielectric constants, optical properties

magnetic properties

Debye temperature, heat capacity, density, melting and boiling points, hardness

thermodynamic properties

strontium oxide (SrO)

band structure, energy gap

effective and polaron masses, Fröhlich coupling constant

impurities and defects

crystal structure, lattice parameters, thermal expansion

phonon dispersion and phonon frequencies

sound velocities, elastic moduli

Young's, shear and bulk modulus, Poisson's ratio

compressibility, Grüneisen parameter, effective ion charge

electrical and thermal transport properties

dielectric constants, optical and photoelectric properties

magnetic properties

Debye temperature, heat capacity, density, melting and boiling points, hardness

thermodynamical properties

barium oxide (BaO)

band structure, energy gap

effective masses, Fröhlich coupling constant

impurities and defects

crystal structure, lattice parameters, thermal expansion

phonon dispersion and phonon frequencies

sound velocities, elastic moduli

bulk modulus, effective ion charge

electrical and thermal transport properties

dielectric constants, optical and photoelectric properties

magnetic properties

Debye temperature, heat capacity, density, melting and boiling points

thermodynamical properties

zinc oxide (ZnO)

- band structure
- energies of symmetry points of the band structure
- energy gaps
- excitons, general
- exciton transition energies
- further exciton data
- special exciton parameters
- biexcitons
- splitting energies
- electron effective masses
- hole effective masses, g -factors
- deformation potentials
- ionization energies of donors
- ionization energies of shallow impurities
- ionization energies of deep impurities
- deep impurity inner transition energies
- Zeeman behavior of impurity transitions
- isotope shift effects of impurity transitions
- quantum efficiencies η and decay times τ of impurity transitions
- energy of traps possibly due to acceptors and donors
- excitons bound to neutral acceptors
- excitons bound to neutral donors
- diffusion coefficients
- wavenumbers of absorption peaks
- ESR spectra
- bound excitons

effective g -values of bound excitons
crystal structure, lattice parameters
distances, ionic radii, further lattice parameters
thermal expansion
effective ionic charge
phonon dispersion and related parameters
phonon wavenumbers: fundamental modes
phonon wavenumbers: combination modes
Raman and surface phonon wavenumbers
sound velocities
elastic moduli and compliances, bulk modulus, compressibility and related parameters
piezoelectrical strain and stress coefficients
electromechanical coupling factor
pyroelectric constants
electronic conductivity and photoconductivity
resistivity, mobility
thermoelectric power
surface conductivity
thermal conductivity
optical properties and spectra
refractive index
isotropic wavelength
dielectric constants
electrooptical constants
light absorption in crystals with admixtures
nonlinear optical properties
magnetic susceptibility
Debye temperature, heat capacity, density, melting point, vapor pressure, hardness
thermodynamical properties

zinc sulfide (ZnS)

band structure, cubic modification
energy gap, cubic modification
exciton energies, cubic modification
exciton and electron-hole liquid binding energies, cubic modification
Fröhlich and exciton-phonon coupling constants cubic modification
critical point and interband transition energies, cubic modification
spin-orbit splitting, g -factor, cubic modification
effective masses, cubic modification
deformation potential, k -linear term, cubic modification
band structure, hexagonal modification
energy gap, hexagonal modification
exciton energies, hexagonal modification
interband transition energies, hexagonal modification
crystal field and spin-orbit splitting, g -factor, hexagonal modification
effective masses, Luttinger parameters, hexagonal modification
energy states of imperfections and impurities, general remarks
shallow donors, ionization energies and g -values
shallow acceptor energies
ionization energies of deep impurities
ionization energies of deep impurities (further data prior to 1980)
deep impurity inner transition energies
crystal field splitting parameter Dq and Racah parameter B of 3d impurities
property: Zeeman behavior of impurity transitions
isotope shift effects of impurity transitions
pressure coefficients of impurity transitions
quantum efficiencies η and decay times τ of impurity transitions
energy and capture cross section σ of traps possibly due to acceptors and donors
emission energies (maxima of emission bands) of impurity-related transitions

native defects: general
native defects: special defects
impurities in ZnS: scandium
impurities in ZnS: titanium
impurities in ZnS: vanadium
impurities in ZnS: chromium
impurities in ZnS: manganese
impurities in ZnS: iron
impurities in ZnS: cobalt
impurities in ZnS: nickel
impurities in ZnS: copper
ground state properties of rare-earth ions
impurities in ZnS: other substitutional impurities
impurities in ZnS: associates
impurities in ZnS: further associated defects
property: impurity (defect) bound excitons
crystal structure, modifications
lattice parameter, cubic modification
lattice parameter, hexagonal modification
lattice parameter, polytypic ZnS and other modifications
transformation temperature and pressure
thermal expansion
interatomic distances, covalent and ion radii

effective charges
electronic polarizability, ionicity
phonon dispersion
phonon wavenumbers, mean square displacements, cubic modification
phonon wavenumbers, hexagonal modification
phonon wavenumbers, polytypic ZnS(4H)
Raman frequencies and wavenumbers
surface optical phonon wavenumber, cubic modification
sound velocities
elastic moduli, cubic modification
elastic moduli, hexagonal modification
elastic compliances, cubic modification
elastic compliances, hexagonal modification
elastic moduli, pressure dependence
bulk modulus
compressibility, effective charges
third-order elastic constants, Young's modulus, Poisson's ratio, Grüneisen parameters
electromechanical coupling coefficients
internal strain, piezoelectric strain and stress constants
(photo)conductivity, resistivity, cubic modification
carrier mobilities, magnetoresistance, diffusion length, cubic modification

thermal conductivity
optical properties
refractive index, cubic modification
refractive index, hexagonal modification
refractive index, polycrystalline ZnS
bulk-photovoltaic effect, thin films
dielectric constant, cubic modification
dielectric constant, hexagonal modification
electrooptical constants
elasto-optical and piezo-optical constants
third order elasto-optical constants
nonlinear optical coefficients
photodielectric effect
energy efficiency of cathodoluminescence
electron yield, electron affinity
photoelectric threshold, work function
plasmon energy of valence band electrons
absorption and reflection in the uv and ir regions
Raman and Faraday effects, multi-phonon spectra
visible luminescence of ZnS
Debye temperature
heat capacity
molar weight and volume, isotopic abundances
hardness, density
melting point
vapor pressure, heat of vaporization
thermodynamical parameters

zinc selenide (ZnSe)

band structure
energies at symmetry points of the band structure
energy gap
exciton energies
temperature and pressure dependence of exciton energies
further exciton parameters
interband transition energies
spin-orbit splitting energies
free carrier effective masses, Fröhlich coupling constant
exciton reduced masses and other exciton parameters
Luttinger parameters, exchange parameter
g-factors
oscillator strengths
exciton Rydberg energy
electron-hole interaction parameter
k-linear term, deformation potentials
shallow donors, ionization energies
shallow donor, excitation energies
chemical and *g*-values of shallow impurities
shallow acceptor ionization energies
shallow acceptor excitation energies
further data on shallow impurities
emission energies
zero-phonon lines

bound exciton transition and binding energies
bound exciton emission peaks
decay times of acceptor-bound-exciton luminescence
splitting and g -values of bound excitons
excitons bound to neutral donors
transitions into excited electronic states of donor-bound-exciton complexes
decay times of bound-exciton luminescence
pressure dependence of bound excitons
emission band maxima
energy and capture cross section σ of traps possibly due to acceptors and donors
ionization energies of deep impurities
deep impurity inner transition energies
pressure coefficients and quantum efficiencies of impurity transitions
3d impurity emission lines
3d impurity crystal field splitting
impurity g -values
spin Hamiltonian parameters
crystal structure, modifications
properties of the rocksalt modification
lattice parameter, thermal expansion
ionic radii, effective charges

phonon dispersion
phonon energies
phonon frequencies
pressure dependence of phonon wavenumbers
energies of local modes
sound velocities
elastic moduli and compliances
compressibility, piezoelectric stress and strain
Young's, shear and bulk moduli
Grüneisen parameters
electrical (photo)conductivity and resistivity
free carrier mobilities, Hall coefficient and magnetoresistance
charge carrier and ion diffusion
thermoelectric power, thermal conductivity
refractive index
absorption coefficient
dielectric constants
Verdet constant
Cotton-Mouton effect, electrooptic and photoelastic coefficients
nonlinear optical properties
radiation damage
magnetic properties
Debye temperature, heat capacity, Schottky barrier heights
density, melting point, hardness
thermodynamical properties

zinc telluride (ZnTe)

band structure, band energies
energy gap
exciton energies
critical point energies, spin-orbit splitting
effective masses
Fröhlich coupling constant, g -factors
diamagnetic shift, k -linear term
Luttinger parameters, deformation potentials
shallow acceptor and donor energies
deep impurities
bound excitons
crystal structure, lattice parameters, thermal expansion
effective charges
phonon dispersion, phonon frequencies and related data
sound velocities, elastic moduli, bulk modulus, compressibility
Grüneisen parameters, internal strain parameter, piezoelectric constant, effective charges
electrical and thermal transport, carrier mobilities
dielectric constants
refractive index, absorption, luminescence
piezoelectric stress coefficient, photoelastic constants, electrooptic coefficient
nonlinear optical properties
heat capacity, Debye temperature, density, melting point, hardness
thermodynamical properties

cadmium oxide (CdO)

band structure

band energies at symmetry points

energy gap

interband transition energies

effective masses, g -factor and related parameters

impurities and defects

crystal structure, lattice parameters, thermal expansion

phonon properties and frequencies, effective ion charge

transport properties, carrier mobilities

optical and photoelectric properties, dielectric constants, plasmon energy

magnetic properties

Debye temperature, heat capacity, melting point, density

thermodynamic properties, vapor pressure, phase diagram

cadmium sulfide (CdS)

band structure, hexagonal modification
valence band energies, hexagonal modification
energy gaps, hexagonal modification
splitting parameters, hexagonal modification
 k -linear terms, hexagonal modification
energy gap pressure and temperature coefficients, hexagonal modification
interband transition energies, hexagonal modification
deformation potentials, hexagonal modification
free carrier effective masses, hexagonal modification
 g -factors, hexagonal modification
diamagnetic shift, Luttinger parameter, deformation potentials,
free excitons, hexagonal modification
further exciton energies, hexagonal modification
exciton polaritons: A-exciton, hexagonal modification
exciton polaritons: B-exciton, hexagonal modification
dense exciton systems, hexagonal modification
biexciton energy, hexagonal modification
electron-hole liquids, highly excited CdS, hexagonal modification
further exciton data, exciton-phonon coupling, oscillator strengths and other parameters
band structure, energy gap, cubic modification
interband transition energies and effective masses, cubic modification
band structure, zincblende modification
ionization and excitation energies of impurities and defects
capture cross-sections of impurities
further data on impurities
impurity (defect) bound excitons
donor-acceptor pairs transitions

crystal structure, modifications
lattice parameters, thermal expansion
phonon dispersion
phonon wavenumbers, mean square displacements
Raman wavenumbers
local modes
sound velocities and absorption
elastic moduli and compliances
piezoelectric stress and strain coefficients
electromechanical coupling factor
vibrational amplitudes, bulk modulus
compressibilities, Grüneisen parameters, effective charges
transport mechanism
intrinsic conductivity and carrier concentrations
electrical and thermal conductivity, resistivity, magnetoresistance
photoconductivity
electron mobilities
hole mobilities
diffusion of carriers and ions
Seebeck and Nernst coefficient
optical properties (general), refractive index and birefringence, Sellmeier coefficients
absorption coefficient, reflectance
dielectric constants
Verdet constant
photoelastic coefficient, nonlinear optics
two photon absorption
optical rectification and bistability
linear and quadratic electrooptic coefficients
Schottky barrier heights
optical and ESR spectra of iron-group-element-impurities
magnetic properties
Debye temperature, heat capacity, density, melting point, hardness
thermodynamic properties, vapor pressure, phase diagram

cadmium selenide (CdSe)

band structure, hexagonal modification
energy gaps, hexagonal modification
valence band splitting parameters, hexagonal modification
energy gap, temperature and pressure coefficients, hexagonal modification
interband transition energies, hexagonal modification
Luttinger parameters, deformation potentials, hexagonal modification
effective masses, Fröhlich coupling constant, hexagonal modification
 g -factors, hexagonal modification
exciton energies, hexagonal modification
excitonic polaritons, oscillator strengths, biexcitons, hexagonal modification
dense exciton systems, hexagonal modification
electronic properties, cubic modification
electronic properties, zincblende modification
impurities and defects: ionization energies
further data on shallow and deep impurities
impurity bound excitons
crystal structure, modifications
lattice parameters, thermal expansion
phonon dispersion
phonon wavenumbers, mean square displacements
local mode wavenumbers
sound velocities
elastic moduli
piezoelectric strain and stress coefficients, electromechanical coupling factor
Young's and bulk modulus, compressibility, effective charges

electrical transport
electrical conductivity, carrier concentration, magnetoresistance
photoconductivity and thermal conductivity
electron mobilities
hole mobility, carrier and ion diffusion
thermoelectric power
optical properties, general, refractive index
isotopic wavelength, Sellmeier coefficients
refractive index, birefringence
absorption, reflection, luminescence
dielectric constants
two photon absorption
optical and ESR spectra of iron-group element impurities
electrooptic and non-linear coefficients
magnetic properties
Debye temperature, heat capacity, density, melting point, hardness
thermodynamical properties, phase diagram

cadmium telluride (CdTe)

band structure
band energies at symmetry points
energy gap
critical point and splitting energies
effective masses
g-factors, *k*-linear terms
Kane and Luttinger parameters of valence band, polaron coupling constant
deformation potentials
excitons
impurities and defects: ionization energies
intrinsic defects and defect complexes
property: energy position and capture cross sections (σ) of traps
bound excitons, donor-acceptor pairs
crystal structure, modifications
lattice parameter, thermal expansion
phonon dispersion, phonon frequencies and wavenumbers, local modes
mean square displacements
sound velocities, elastic moduli
bulk modulus, compressibility, ionicity, effective ion charge
Grüneisen parameter, stress and strain coefficient
electrical and thermal transport, carrier mobilities
optical properties, refractive index, dielectric constants, two-photon absorption
Debye temperature, heat capacity, density, melting point, hardness
thermodynamic properties, vapor pressure, phase diagram

mercury oxide (HgO)

crystal structure, physical properties

mercury sulfide (HgS)

crystal structure, modifications

band energies, impurities: α -HgS (trigonal) (red cinnabar)

lattice properties: α -HgS (trigonal) (red cinnabar)

transport properties: α -HgS (trigonal) (red cinnabar)

optical properties, dielectric constants: α -HgS (trigonal) (red cinnabar)

crystal structure, lattice parameters, bulk modulus: β -HgS (zincblende structure)

band structure, energy gap, effective masses: β -HgS (zincblende structure)

further lattice properties: β -HgS (zincblende structure)

transport, optical and further properties: β -HgS (zincblende structure)

Debye temperature, heat capacity, melting point, density, hardness

thermodynamic properties

mercury selenide (HgSe)

band structure, energy gap

interband transition and splitting energies, effective masses, g -factor

Luttinger and Kane parameters of the valence band

impurities and defects

crystal structure, lattice parameters

phonon dispersion and phonon wavenumbers

elastic moduli

effective charge, bulk modulus, compressibility

electrical conductivity, electron mobility

optical properties, dielectric constants

Debye temperature, heat capacity, melting point, density, hardness

thermodynamical properties, vapor pressure, phase diagram

mercury telluride (HgTe)

band structure, band energies at symmetry points
energy gap
critical point energies
spin-orbit splitting, k -linear term
effective masses
 g -factors
Luttinger and Kane parameters
impurities and defects
crystal structure, modifications
lattice parameters
thermal expansion
phonon dispersion, phonon energies and wavenumbers
elastic moduli, sound velocity
bulk modulus, effective charge, Grüneisen parameter
electrical transport, conductivity, mobility
optical properties, dielectric constants
Debye temperature, melting point, density, heat capacity, hardness
thermodynamical properties, vapor pressure, phase diagram

solid solutions of II–VI compounds

properties of IIA–VIB compounds

ZnS_{1-x}Se_x

electronic properties
impurities and defects
lattice properties
transport properties
optical properties

ZnS_{1-x}Te_x

physical properties

ZnSe_xTe_{1-x}

electronic properties
impurities and defects
transport and optical properties

CdS_{1-x}Se_x

electronic properties
impurities and defects, lattice and transport properties
optical properties

CdS_{1-x}Te_x

physical properties

CdSe_xTe_{1-x}

electronic properties
impurities and defects
transport and optical properties

Zn_xCd_{1-x}O

physical properties

Zn_xCd_{1-x}S

electronic properties
impurities and defects
lattice parameters, phase diagrams
transport properties
optical properties

Zn_xCd_{1-x}Se

electronic properties
impurities and defects
transport properties
optical properties

Zn_xCd_{1-x}Te

electronic properties
impurities and defects
lattice properties
transport properties
optical properties

Zn_{1-y}Cd_yS_xSe_{1-x}

physical properties

Zn_{1-y}Cd_ySe_xTe_{1-x}

physical properties

Cd(Te,Se,S)

physical properties

Zn(Te,Se,S)

physical properties

Zn_xHg_{1-x}Se

physical properties

Hg_{1-x}Zn_xTe

physical properties

Hg_{1-x}Cd_xSe

electronic properties

lattice properties

transport and optical properties

Hg_{1-x}Cd_xTe

band structure, energy gap

interband transition energies, further band parameters

effective masses

impurity levels

lattice properties

transport properties

optical properties

I–VII compounds

comparative tables on crystal structure of phases at normal conditions

comparative tables on crystal structure of high temperature phases

chemical bond, disorder and melting

cuprous fluoride (CuF)

physical properties

cuprous chloride (γ -CuCl)

band structure

energy gaps

critical point energies

exciton energies, oscillator strength, polariton dispersion

transition energies to higher excited exciton states

exciton splitting energies

spin-orbit splitting energies

exchange energies

exciton radii and binding energy

biexcitons

free carrier effective masses

exciton effective masses

g-factors

deformation potentials

localized excitons

further remarks to electronic properties

electronic properties of NaCl-type CuCl

crystal structure, space group

lattice parameter, thermal expansion, compressibility

phonon dispersion

phonon frequencies, wavenumbers and related data

mean square displacements, Debye-Waller factors, line widths

elastic moduli, mode Grüneisen parameters, effective charges

compressibility, bulk modulus, internal strain parameter

ambipolar diffusion of excitons

ionic conductivity

optical properties, dielectric constants, refractive index

piezoelectric stress coefficient

electrooptic and piezooptic constants, piezobirefringence

second-order nonlinear dielectric susceptibility

third-order nonlinear dielectric susceptibility; electromagnetic coupling constant

magnetic susceptibility

Debye temperature, melting point, density

cuprous bromide (γ -CuBr)

band structure, energy gaps
exciton energies
higher exciton states
edge exciton energies
exciton splitting energies
spin-orbit splitting energy
exciton exchange energies
exciton radii, binding energies and other exciton parameters
effective masses
biexciton parameters
Luttinger parameters, g -factors
deformation potentials
electronic properties of NaCl-type CuBr
crystal structure, high-pressure modifications
lattice parameters, thermal expansion
phonon dispersion and frequencies, Debye-Waller factor
elastic moduli
compressibility, bulk modulus, internal strain, Grüneisen parameter, effective charges
ionic conductivity
dielectric constants, refractive index
birefringence, electrooptic and elasto-optic constants
second order nonlinear parameters
magnetic susceptibility
Debye temperature, heat capacity, melting point, density

cuprous iodide (γ -CuI)

band structure, energy gap
exciton transition and splitting energies
spin-orbit splitting energy
exciton radii, binding energy and other exciton parameters
effective masses
 g -factors
deformation potentials
electronic properties of NaCl-type CuI
crystal structure, high pressure modifications
lattice parameters, thermal expansion
phonon dispersion and frequencies and related data, Debye-Waller factors
elastic moduli, compressibility, bulk modulus, internal strain, Grüneisen
parameter, effective charge
ionic conductivity
dielectric constants, refractive index
birefringence, piezoelectric, piezooptic and other optical constants
magnetic susceptibility
Debye temperature, heat capacity, melting point, density

silver monofluoride (AgF)

characterization, band structure and energies
crystal structure, lattice parameters, phonon frequencies
dielectric constants, refractive index
Debye temperature, melting point, density

silver chloride (AgCl)

band structure
energy gaps, indirect edge
deformation potential
exciton binding energy, exchange interaction, g -factor
energy gaps, direct edge
effective masses, further band parameters
further remarks to band structure
impurities and intrinsic defects: bound excitons
impurities and intrinsic defects: infrared absorption spectra
impurities and intrinsic defects: transient infrared absorption spectra
impurities and intrinsic defects: self-trapped exciton and hole state (STE, STH)
impurities and intrinsic defects: ODMR spectra
crystal structure, lattice parameters, thermal expansion
phonon dispersion, frequencies and wavenumbers
elastic moduli and compliances
bulk modulus, compressibility. mode Grüneisen parameters
electrical and thermal transport
refractive index, dielectric constants
reflectivity, luminescence
Debye temperature, heat capacity, melting point, density

silver bromide (AgBr)

- band structure
- band gap, indirect edge
- exciton energies
- g*-factors
- band gap, direct edge
- effective masses
- deformation potentials and related parameters
- biexciton parameters
- further remarks to electronic properties
- impurities and intrinsic defects: bound excitons
- impurities and intrinsic defects: infrared absorption spectra
- impurities and intrinsic defects: transient infrared absorption spectra
- crystal structure, high pressure modifications, lattice parameters, thermal expansion
- phonon dispersion
- phonon frequencies and wavenumbers, Debye-Waller factors and related data
- elastic moduli and compliances
- Grüneisen parameters, bulk modulus, compressibility
- electrical and ionic transport properties
- optical properties, dielectric constants
- Debye temperature, heat capacity, melting point, density
- physical properties of $\text{AgBr}_{1-x}\text{Cl}_x$ and $\text{AgBr}_{1-x}\text{I}_x$ mixed crystals

silver iodide (AgI)

band structure, energy gaps: β -AgI (wurtzite)
edge exciton transition energies: β -AgI (wurtzite)
transitions to higher excited exciton states: β -AgI (wurtzite)
spin-orbit, crystal field and longitudinal–transverse splitting energies (β -AgI)
exciton radius and binding energies
effective and reduced masses
electronic properties of γ -AgI (zincblende)
electronic properties of f.c.c.-AgI (NaCl-type)
crystal structure, high pressure modifications, lattice parameters
phonon dispersion and frequencies, Debye-Waller factors
sound velocities, elastic moduli and compliances, compressibility and related data
lattice properties of γ -AgI and f.c.c.-AgI
ionic transport and related properties
dielectric constants
piezoelectric stress coefficient
far-infrared reflectivity and transmission
Debye temperature, melting point, density, heat capacity
AgBr_{1-x}I_x, AgI_{1-x}Cl_x and Ag_xCu_{1-x}I mixed crystals

semimagnetic semiconductors

composition and crystal structure of ternary bulk semimagnetic semiconductors
definitions, general properties, structure, general remarks
general remarks and important formulae for narrow gap semiconductors
general remarks and important formulae for wide gap semiconductors

mercury manganese telluride – $\text{Hg}_{1-x}\text{Mn}_x\text{Te}$

band structure, general
band structure parameters
effective mass, g -factor, exchange constants
impurities
lattice properties, dielectric constants
transport mechanisms, insulator-metal transition
optical and magnetic properties

mercury manganese selenide – $\text{Hg}_{1-x}\text{Mn}_x\text{Se}$

electronic properties
transport and magnetic properties

mercury manganese sulfide – $\text{Hg}_{1-x}\text{Mn}_x\text{S}$

physical properties

cadmium manganese telluride – $\text{Cd}_{1-x}\text{Mn}_x\text{Te}$

electronic properties

lattice, transport and magnetic properties

cadmium manganese selenide – $\text{Cd}_{1-x}\text{Mn}_x\text{Se}$

physical properties

cadmium manganese sulfide – $\text{Cd}_{1-x}\text{Mn}_x\text{S}$

physical properties

zinc manganese telluride – $\text{Zn}_{1-x}\text{Mn}_x\text{Te}$

physical properties

zinc manganese selenide - $\text{Zn}_{1-x}\text{Mn}_x\text{Se}$

physical properties

zinc manganese sulfide – $\text{Zn}_{1-x}\text{Mn}_x\text{S}$

physical properties

quaternary alloys of II-VI semiconductors with Mn

physical properties

II-VI semimagnetic semiconductors with transition metal ions other than Mn

general properties

mercury iron telluride ($\text{Hg}_{1-x}\text{Fe}_x\text{Te}$)

physical properties

mercury iron selenide ($\text{Hg}_{1-x}\text{Fe}_x\text{Se}$)

physical properties

mercury iron sulfide ($\text{Hg}_{1-x}\text{Fe}_x\text{S}$)

physical properties

cadmium iron telluride ($\text{Cd}_{1-x}\text{Fe}_x\text{Te}$)

physical properties

cadmium iron selenide ($\text{Cd}_{1-x}\text{Fe}_x\text{Se}$)

physical properties

cadmium iron sulfide ($\text{Cd}_{1-x}\text{Fe}_x\text{S}$)

physical properties

zinc iron telluride ($Zn_{1-x}Fe_xTe$)

physical properties

zinc iron selenide ($Zn_{1-x}Fe_xSe$)

physical properties

zinc iron sulfide ($Zn_{1-x}Fe_xS$)

physical properties

mercury cobalt selenide ($Hg_{1-x}Co_xSe$)

physical properties

cadmium cobalt telluride ($Cd_{1-x}Co_xTe$)

physical properties

cadmium cobalt selenide ($Cd_{1-x}Co_xSe$)

physical properties

cadmium cobalt sulfide ($Cd_{1-x}Co_xS$)

physical properties

zinc cobalt telluride ($\text{Zn}_{1-x}\text{Co}_x\text{Te}$)

physical properties

zinc cobalt selenide ($\text{Zn}_{1-x}\text{Co}_x\text{Se}$)

physical properties

zinc cobalt sulfide ($\text{Zn}_{1-x}\text{Co}_x\text{S}$)

physical properties

mercury chromium selenide ($\text{Hg}_{1-x}\text{Cr}_x\text{Se}$)

physical properties

cadmium chromium telluride ($\text{Cd}_{1-x}\text{Cr}_x\text{Te}$)

physical properties

cadmium chromium sulfide ($\text{Cd}_{1-x}\text{Cr}_x\text{S}$)

physical properties

zinc chromium telluride ($\text{Zn}_{1-x}\text{Cr}_x\text{Te}$)

physical properties

zinc chromium selenide ($\text{Zn}_{1-x}\text{Cr}_x\text{Se}$)

physical properties

zinc chromium sulfide ($\text{Zn}_{1-x}\text{Cr}_x\text{S}$)

physical properties

IV-VI semimagnetic semiconductors with Mn, Eu and Gd

general properties

lead manganese telluride – $\text{Pb}_{1-x}\text{Mn}_x\text{Te}$

physical properties

lead manganese selenide – $\text{Pb}_{1-x}\text{Mn}_x\text{Se}$

physical properties

lead manganese sulfide – $\text{Pb}_{1-x}\text{Mn}_x\text{S}$

physical properties

lead tin manganese selenide ($\text{Pb}_{1-x-y}\text{Sn}_y\text{Mn}_x\text{Se}$)

physical properties

tin manganese telluride – $\text{Sn}_{1-x}\text{Mn}_x\text{Te}$

physical properties

germanium manganese telluride – $\text{Ge}_{1-x}\text{Mn}_x\text{Te}$

physical properties

lead tin manganese telluride ($\text{Pb}_{1-x-y}\text{Sn}_y\text{Mn}_x\text{Te}$)

physical properties

lead europium telluride ($\text{Pb}_{1-x}\text{Eu}_x\text{Te}$)

physical properties

lead europium selenide ($\text{Pb}_{1-x}\text{Eu}_x\text{Se}$)

physical properties

lead europium sulfide ($\text{Pb}_{1-x}\text{Eu}_x\text{S}$)

physical properties

lead gadolinium telluride ($\text{Pb}_{1-x}\text{Gd}_x\text{Te}$)

physical properties

tin gadolinium telluride ($\text{Sn}_{1-x}\text{Gd}_x\text{Te}$)

physical properties

indium manganese arsenide ($\text{In}_{1-x}\text{Mn}_x\text{As}$)

physical properties

gallium manganese arsenide ($\text{Ga}_{1-x}\text{Mn}_x\text{As}$)

physical properties

II-V manganese compounds

general remarks

cadmium manganese arsenide ($\text{Cd}_{1-x}\text{Mn}_x$)₃As₂

physical properties

zinc manganese arsenide ($\text{Zn}_{1-x}\text{Mn}_x$)₃As₂

physical properties